

**Product data sheet** 

### 1. General description

Planar passivated sensitive gate four quadrant triac in a SOT78 (TO-220AB) plastic package intended for use in general purpose bidirectional switching and phase control applications. This sensitive gate "series E" triac is intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

#### 2. Features and benefits

- · High blocking voltage capability
- Direct triggering from low power drivers and logic ICs
- · Planar passivated for voltage ruggedness and reliability
- Triggering in all four quadrants
- Sensitive gate

### 3. Applications

- General purpose motor control
- General purpose switching

### 4. Quick reference data

Symbol	Parameter	Conditions	Values				Unit
Absolute	maximum rating						
$V_{\text{DRM}}$	repetitive peak off-state voltage		600			V	
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>mb</sub> ≤ 99 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	12			A	
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	95		A		
T <sub>j</sub>	junction temperature		125		°C		
Symbol	Parameter	Conditions	Min Typ Max		Max	Unit	
Static ch	aracteristics	·					
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T2+ G+; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>		-	2.5	10	mA
		V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T2+ G-; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>		-	4	10	mA
		V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T2- G-; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>		-	5	10	mA
		V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T2- G+; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>		-	11	25	mA
Dynamic	characteristics	·					
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 402 V; $T_j$ = 125 °C; ( $V_{DM}$ = 67% of $V_{DRM}$ ); exponential waveform; gate open circuit		-	150	-	V/µs

# 5. Pinning information

	Pinning info			
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1	mb	
2	T2	main terminal 2		
3	G	gate		sym051
mb	T2	mounting base; main terminal 2	نــــــ	Symoor
			1 2 3	

# 6. Ordering information

Table 3. Ordering information				
Type number	Package			
	Name	Description	Version	
BT138-600E	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78	

# 7. Marking

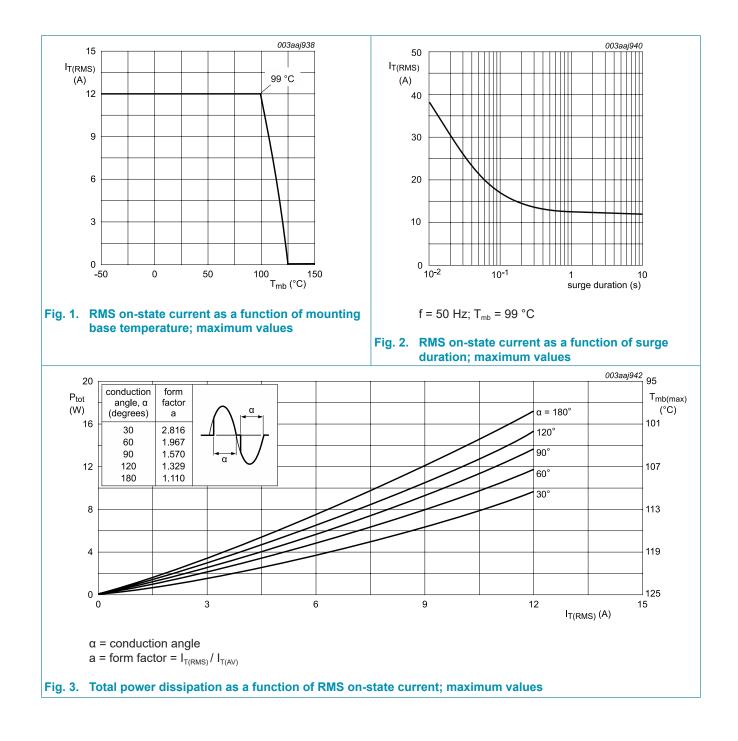
Table 4. Marking codes	
Type number	Marking codes
BT138-600E	BT138-600E

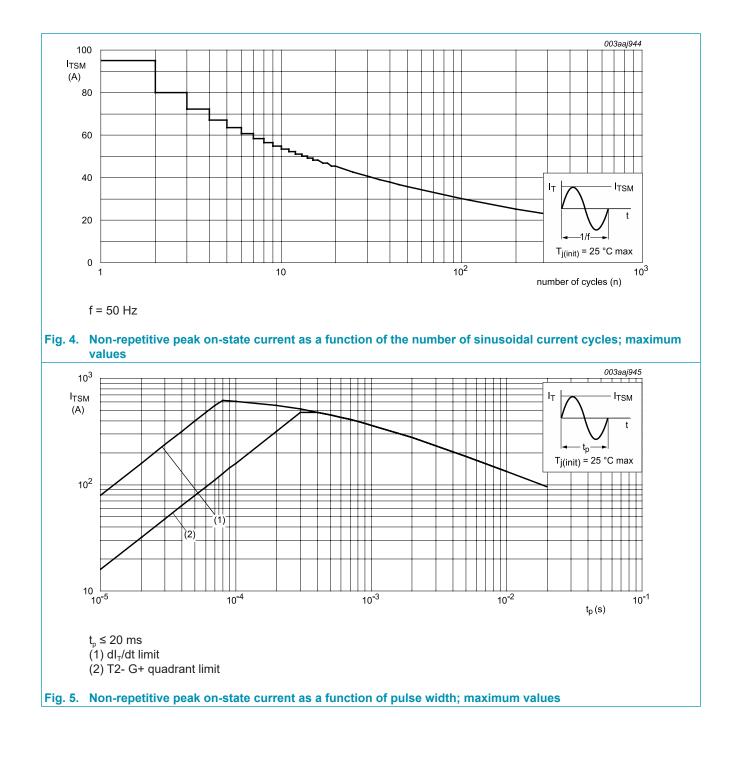
# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

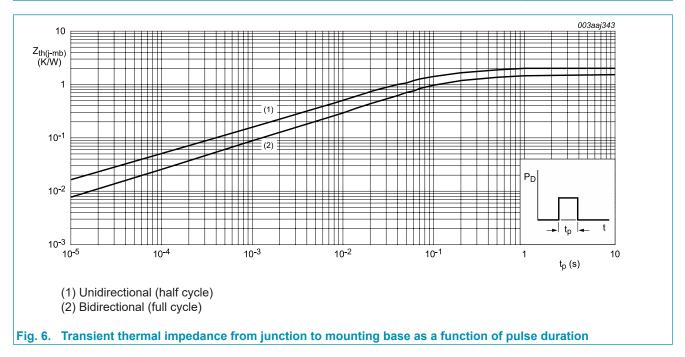
Symbol	Parameter	Conditions	Values	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage		600	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>mb</sub> ≤ 99 °C; <u>Fig 1; Fig 2; Fig 3</u>	12	A
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 20 ms; <u>Fig 4</u> ; <u>Fig 5</u>	95	A
		full sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 16.7 ms	105	A
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; sine-wave pulse	45	A <sup>2</sup> s
dl <sub>T</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 20 mA; T2+ G+	50	A/µs
		I <sub>G</sub> = 20 mA; T2+ G-	50	A/µs
		I <sub>G</sub> = 20 mA; T2- G-	50	A/µs
		I <sub>G</sub> = 50 mA; T2- G+	10	A/µs
I <sub>GM</sub>	peak gate current		2	А
P <sub>GM</sub>	peak gate power		5	W
$P_{G(AV)}$	average gate power	over any 20 ms period	0.5	W
T <sub>stg</sub>	storage temperature		-40 to 150	°C
Tj	junction temperature		125	°C





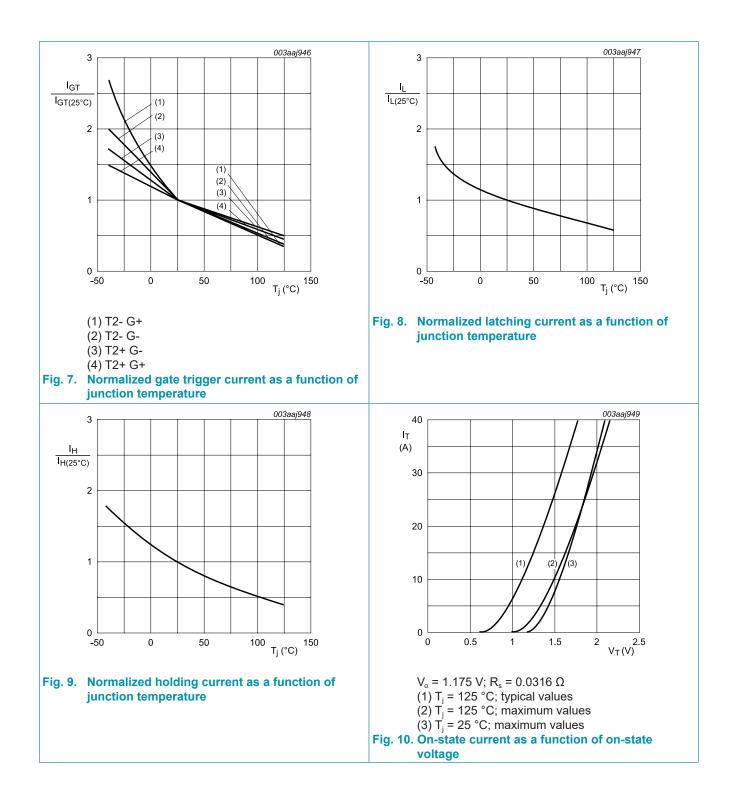
## 9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	full cycle; <u>Fig 6</u>	-	-	1.5	K/W
		half cycle; <u>Fig 6</u>	-	-	2	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient	in free air	-	60	-	K/W



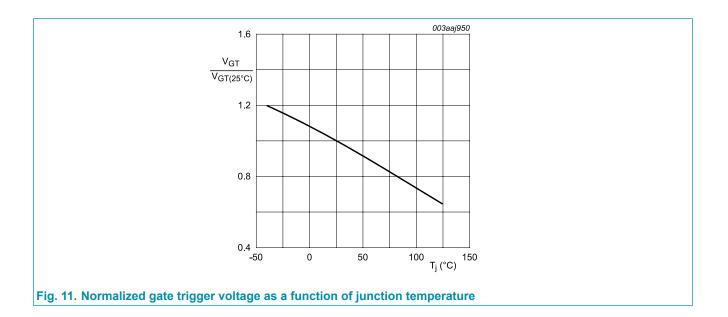
## **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics	· · · ·				
I <sub>GT</sub>	gate trigger current	$V_{D} = 12 \text{ V; } I_{T} = 0.1 \text{ A; } \text{T2+ G+;}$ $T_{j} = 25 \text{ °C; } \text{Fig. 7}$	-	2.5	10	mA
		$V_{D}$ = 12 V; I <sub>T</sub> = 0.1 A; T2+ G-; T <sub>j</sub> = 25 °C; Fig. 7	-	4	10	mA
		$V_{D}$ = 12 V; I <sub>T</sub> = 0.1 A; T2- G-; T <sub>j</sub> = 25 °C; Fig. 7	-	5	10	mA
		$V_{D}$ = 12 V; I <sub>T</sub> = 0.1 A; T2- G+; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	11	25	mA
IL	latching current	$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; \text{ T2+ G+};$ $T_j = 25 \text{ °C}; \text{ Fig. 8}$	-	-	30	mA
		$V_{D}$ = 12 V; I <sub>G</sub> = 0.1 A; T2+ G-; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	-	40	mA
		$V_{D}$ = 12 V; I <sub>G</sub> = 0.1 A; T2- G-; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	-	30	mA
		$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; \text{ T2- G+};$ T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	-	40	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	-	30	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 15 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	1.4	1.65	V
V <sub>GT</sub>	gate trigger voltage	$V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}; T_{j} = 25 \text{ °C};$ Fig. 11	-	0.7	1	V
		$V_{D} = 400 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 125 \text{ °C};$ Fig. 11	0.25	0.4	-	V
I <sub>D</sub>	off-state current	$V_{\rm D} = 600 \text{ V}; \text{ T}_{\rm j} = 125 \text{ °C}$	-	0.1	0.5	mA
Dynamic	characteristics	· · ·	I			
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 402 V; $T_j$ = 125 °C; ( $V_{DM}$ = 67% of $V_{DRM}$ ); exponential waveform; gate open circuit	-	150	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$I_{TM} = 16 \text{ A}; V_D = 600 \text{ V}; I_G = 0.1 \text{ A}; dI_G/dt = 5 \text{ A}/\mu\text{s}$	-	2	-	μs

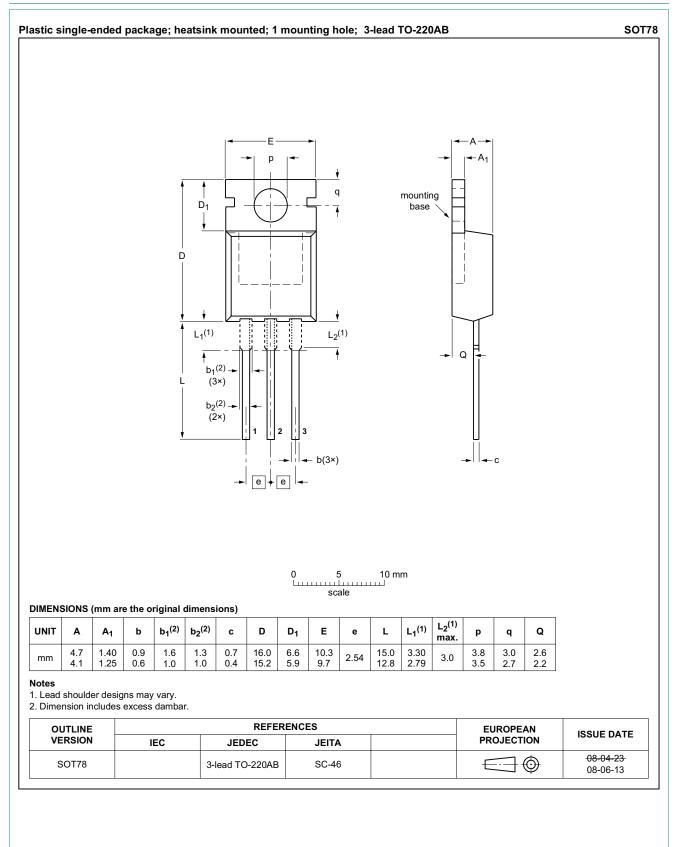


4Q Triac

BT138-600E



### **11. Package outline**



BT138-600E Product data sheet

## 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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